

BC860

Rev.F Apr.-2017

SOT-23

PNP

Silicon PNP transistor in a SOT-23 Plastic Package.

$V_{CE(sat)}$

High current gain, Low collector-emitter saturation voltage.

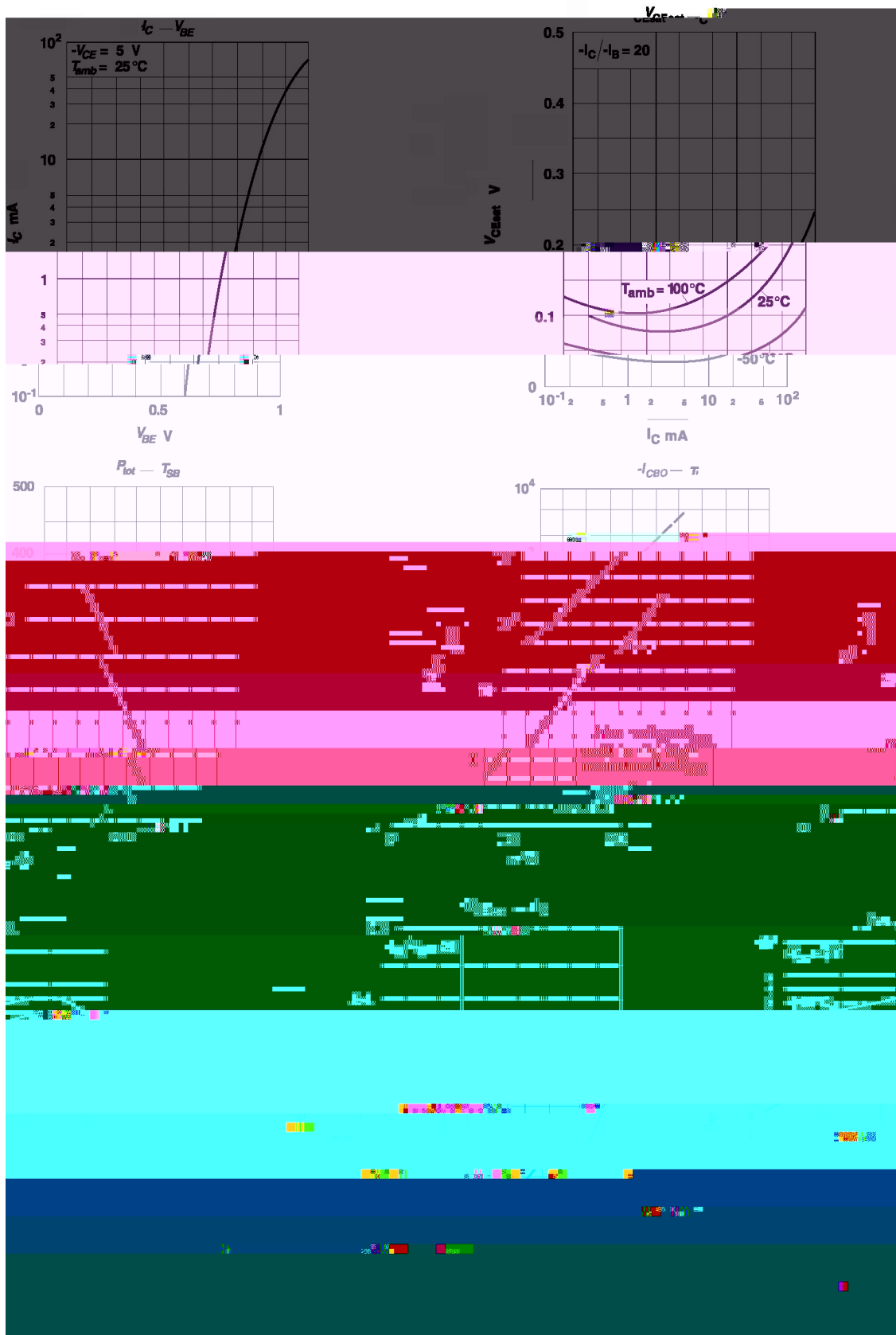
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-45	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-100	mA
Collector Power Dissipation	P_C	350	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=-10mA$ $I_B=0$	-45			V
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=-10 A$ $I_E=0$	-50			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=-10 A$ $I_C=0$	-5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-30V$ $I_E=0$			-0.015	A
DC Current Gain	h_{FE}	$V_{CE}=-5.0V$ $I_C=-2.0mA$	125		800	
Collector to Emitter Saturation Voltage	$V_{CE(sat)(1)}$	$I_C=-10mA$ $I_B=-0.5mA$		-0.075	-0.3	V
	$V_{CE(sat)(2)}$	$I_C=-100mA$ $I_B=-5.0mA$		-0.25	-0.65	V
Base to Emitter Saturation Voltage	$V_{BE(sat)(1)}$	$I_C=-10mA$ $I_B=-0.5mA$		-0.7		V
	$V_{BE(sat)(2)}$	$I_C=-100mA$ $I_B=-5.0mA$		-0.85		V
Base to Emitter Voltage	$V_{BE(1)}$	$V_{CE}=-5.0V$ $I_C=-2.0mA$	-0.6	-0.65	-0.75	V
	$V_{BE(2)}$	$V_{CE}=-5.0V$ $I_C=-10mA$			-0.82	V
Transition Frequency	f_T	$V_{CE}=-5.0V$ $I_C=-10mA$ $f=100MHz$		150		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V$ $I_E=0$ $f=1.0MHz$		4.5		pF
Noise Figure	NF	$V_{CE}=-5.0V$ $I_C=-200 A$ $R_g=10K$ $f=1.0KHz$			4.0	dB

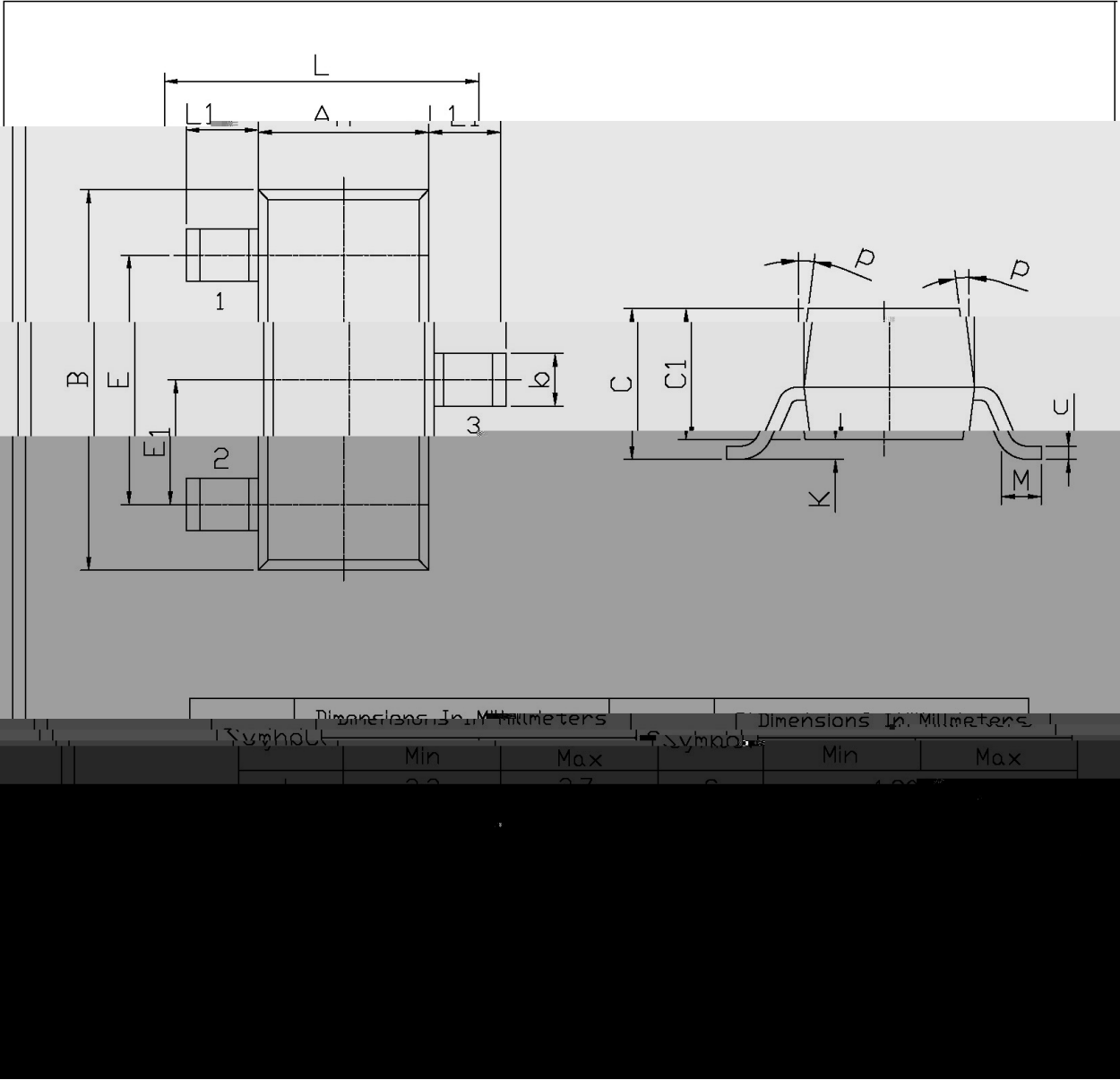
/ Electrical Characteristic Curve



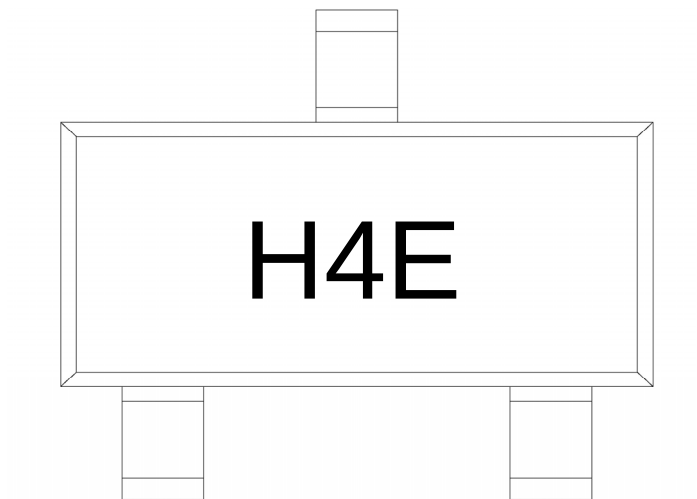
/ Package Dimensions

SOT-23

单位: mm



/ Marking Instructions



H

4E

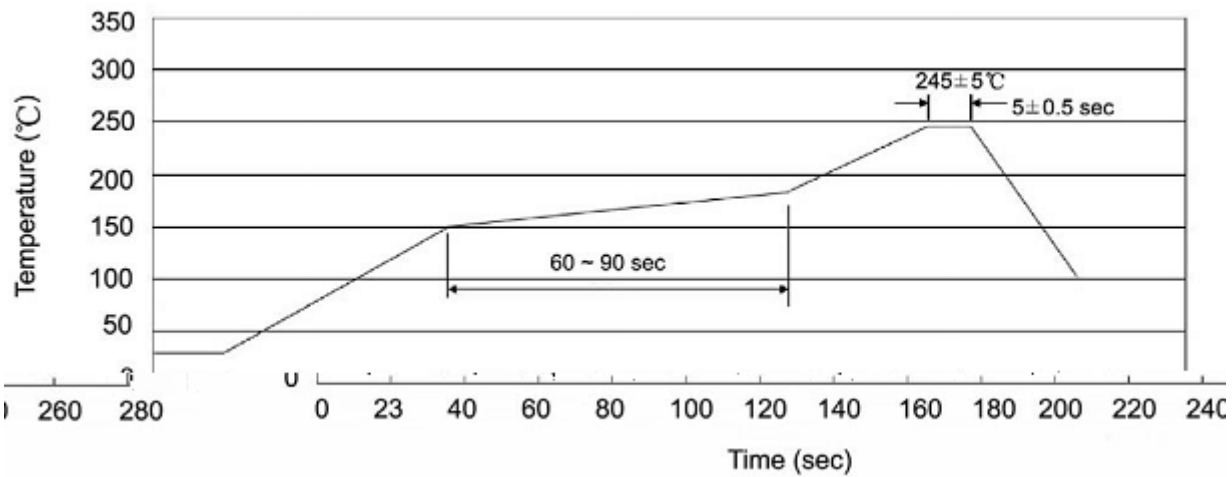
Note:

H: Company Code.

4E: Product Type Code



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Note:

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|---|-------|-----|----|-----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5

10±1 sec.

Temp.:260±5

Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱

/ Notices